

PNP 500 mA, 50 V resistor-equipped transistor; R1 = 2.2 k $\Omega$ , R2 = 10 k $\Omega$ 

Rev. 3 — 30 August 2010

**Product data sheet** 

## 1. Product profile

### 1.1 General description

500 mA PNP Resistor-Equipped Transistor (RET) in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package.

NPN complement: PDTD123YT.

#### 1.2 Features and benefits

- 500 mA output current capability
- Built-in bias resistors
- Simplifies circuit design
- Reduces component count

#### 1.3 Applications

- Digital application in automotive and industrial segments
- Control of IC inputs

#### 1.4 Quick reference data

#### Table 1.Quick reference data

Symbol Conditions Unit Parameter Min Тур Max VCEO collector-emitter voltage open base ---50 V  $I_{O}$ output current --500 mΑ -R1 2.2 2.86 bias resistor 1 (input) 1.54 kΩ R2/R1 bias resistor ratio 4.1 4.55 5

- Reduces pick and place costs
- ±10 % resistor ratio tolerance
- AEC-Q101 qualified
- Cost-saving alternative for BC807 series in digital applications
- Switching loads



PNP 500 mA, resistor-equipped transistor; R1 = 2.2 k $\Omega$ , R2 = 10 k $\Omega$ 

## 2. Pinning information

Table 2.	Pinning		
Pin	Description	Simplified outline	Graphic symbol
1	input (base)	_	
2	GND (emitter)	3	3
3	output (collector)	1 2 006aaa144	1 R1 R2 sym003

## 3. Ordering information

Table 3.         Ordering information					
Type number	Package				
	Name	Description	Version		
PDTB123YT	-	plastic surface-mounted package; 3 leads	SOT23		

### 4. Marking

Table 4. Marking codes	
Type number	Marking code <sup>[1]</sup>
PDTB123YT	*7Y

- [1] \* = -: made in Hong Kong
  - \* = p: made in Hong Kong
  - \* = t: made in Malaysia
  - \* = W: made in China

## 5. Limiting values

#### Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CBO</sub>	collector-base voltage	open emitter	-	-50	V
V <sub>CEO</sub>	collector-emitter voltage	open base	-	-50	V
V <sub>EBO</sub>	emitter-base voltage	open collector	-	-5	V
VI	input voltage				
	positive		-	+5	V
	negative		-	-12	V
lo	output current		-	-500	mA

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#### Table 5. Limiting values ...continued

In accordance with the Absolute Maximum Rating System (IEC 60134).

			,		
Symbol	Parameter	Conditions	Min	Max	Unit
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$	<u>[1]</u> _	250	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-65	+150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

## 6. Thermal characteristics

Table 6.	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	<u>[1]</u> -	-	500	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

## 7. Characteristics

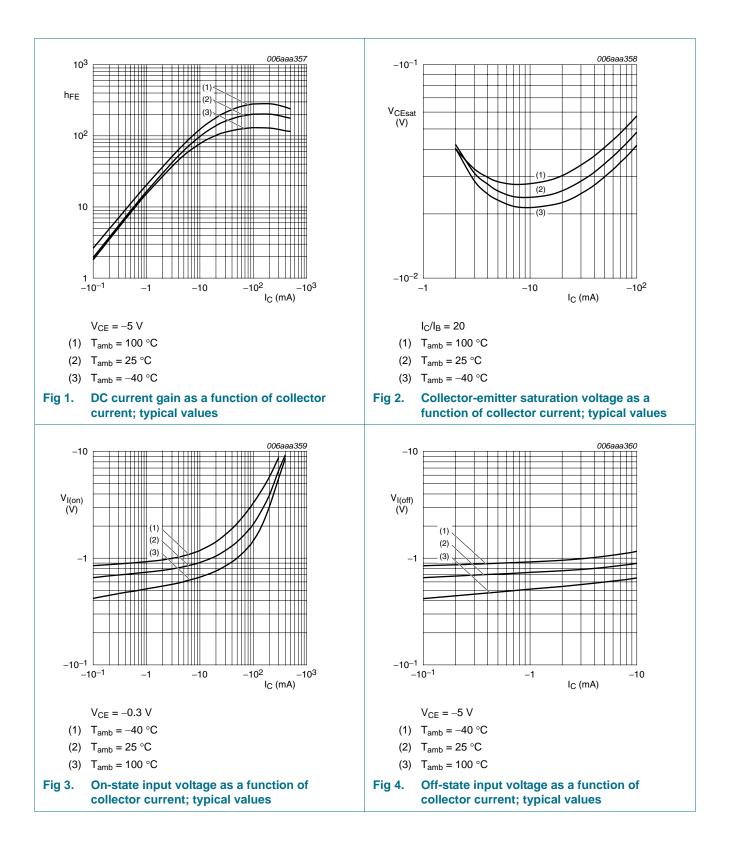
$T_{amb} = 25$	$T_{amb} = 25 \ ^{\circ}C$ unless otherwise specified.					
Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
I <sub>CBO</sub>	collector-base	$V_{CB}$ = $-40$ V; $I_{E}$ = 0 A	-	-	-100	nA
	cut-off current	$V_{CB} = -50$ V; $I_E = 0$ A	-	-	-100	nA
I <sub>CEO</sub>	collector-emitter cut-off current	$V_{CE} = -50 \text{ V}; \text{ I}_{B} = 0 \text{ A}$	-	-	-0.5	μΑ
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; \text{ I}_{C} = 0 \text{ A}$	-	-	-0.65	mA
h <sub>FE</sub>	DC current gain	$V_{CE} = -5 V;$ $I_{C} = -50 mA$	70	-	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	I <sub>C</sub> = −50 mA; I <sub>B</sub> = −2.5 mA	-	-	-0.3	V
V <sub>I(off)</sub>	off-state input voltage	$V_{CE} = -5 V;$ $I_{C} = -100 \ \mu A$	-0.4	-0.6	-1.0	V
V <sub>I(on)</sub>	on-state input voltage	$V_{CE} = -0.3 \text{ V};$ $I_{C} = -20 \text{ mA}$	-0.5	-1.0	-1.4	V
R1	bias resistor 1 (input)		1.54	2.2	2.86	kΩ
R2/R1	bias resistor ratio		4.1	4.55	5	
C <sub>c</sub>	collector capacitance	$V_{CB} = -10 V;$ $I_E = i_e = 0 A;$ f = 100 MHz	-	11	-	pF

Table 7.Characteristics $T_{\rm exp} = 25 \ \%$  unless otherwise species

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# PDTB123YT

#### PNP 500 mA, resistor-equipped transistor; R1 = 2.2 k $\Omega$ , R2 = 10 k $\Omega$



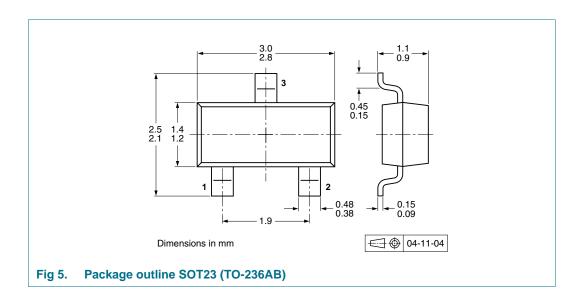
PNP 500 mA, resistor-equipped transistor; R1 = 2.2 k $\Omega$ , R2 = 10 k $\Omega$ 

### 8. Test information

#### 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

### 9. Package outline



## **10. Packing information**

#### Table 8. Packing methods

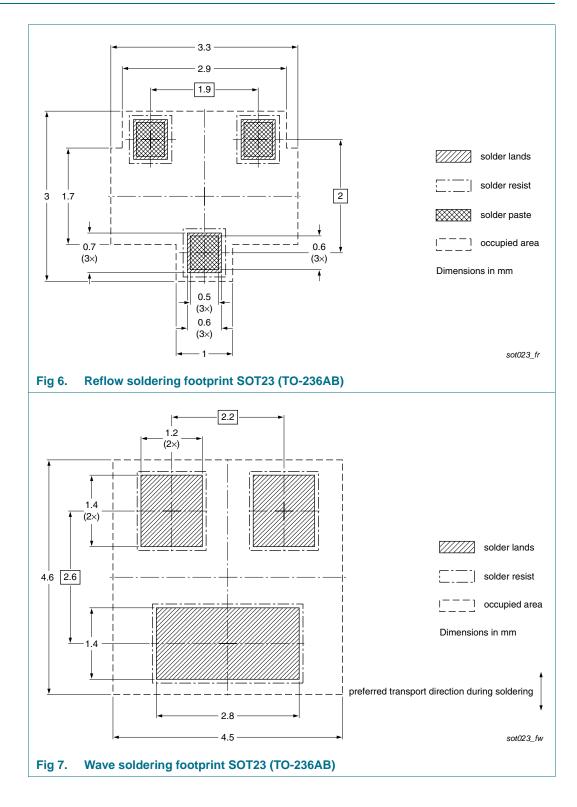
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing	quantity
			3000	10000
PDTB123YT	SOT23	4 mm pitch, 8 mm tape and reel	-215	-235

[1] For further information and the availability of packing methods, see Section 14.

PNP 500 mA, resistor-equipped transistor; R1 = 2.2 k $\Omega$ , R2 = 10 k $\Omega$ 

### 11. Soldering



**PNP 500 mA, resistor-equipped transistor;** R1 = 2.2 k $\Omega$ , R2 = 10 k $\Omega$ 

## 12. Revision history

Table 9. Revision h	istory			
Document ID	Release date	Data sheet status	Change notice	Supersedes
PDTB123YT v.3	20100830	Product data sheet	-	PDTB123Y_SER_2
Modifications:	<ul> <li>Type number</li> </ul>	ers PDTB123YK and PDTB	123YS deleted.	
	• Table 7 "Cha	aracteristics": unit for V <sub>CEsat</sub>	changed from mV to \	Ι.
	<ul> <li>Section 8 "T</li> </ul>	est information": added.		
	Section 11 "	Soldering": added.		
	<ul> <li>Section 13 "</li> </ul>	Legal information": updated	l.	
PDTB123Y_SER_2	20091116	Product data sheet	-	PDTB123Y_SER_1
PDTB123Y_SER_1	20050427	Product data sheet	-	-

## 13. Legal information

#### 13.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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#### **PNP 500 mA, resistor-equipped transistor;** $R1 = 2.2 \text{ k}\Omega$ , $R2 = 10 \text{ k}\Omega$

**Quick reference data** — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

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## PDTB123YT

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